Applied Superconductivity:

Josephson Effect and Superconducting Electronics

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Contents

	Pref	face		xxi
I	Fou	ndatio	ns of the Josephson Effect	1
1	Mac	roscopi	ic Quantum Phenomena	3
	1.1	The M	lacroscopic Quantum Model	3
		1.1.1	Coherent Phenomena in Superconductivity	3
		1.1.2	Macroscopic Quantum Currents in Superconductors	12
		1.1.3	The London Equations	18
	1.2	Flux Q	Quantization	24
		1.2.1	Flux and Fluxoid Quantization	26
		1.2.2	Experimental Proof of Flux Quantization	28
		1.2.3	Additional Topic: Rotating Superconductor	30
	1.3	Joseph	son Effect	32
		1.3.1	The Josephson Equations	33
		1.3.2	Josephson Tunneling	37
2	JJs:	The Ze	ero Voltage State	43
	2.1	Basic	Properties of Lumped Josephson Junctions	44
		2.1.1	The Lumped Josephson Junction	44
		2.1.2	The Josephson Coupling Energy	45
		2.1.3	The Superconducting State	47
		2.1.4	The Josephson Inductance	49
		2.1.5	Mechanical Analogs	49
	2.2	Short.	Josephson Junctions	50
		2.2.1	Quantum Interference Effects – Short Josephson Junction in an Applied Mag- netic Field	50

		2.2.2	The Fraunhofer Diffraction Pattern	54
		2.2.3	Determination of the Maximum Josephson Current Density	58
		2.2.4	Additional Topic: Direct Imaging of the Supercurrent Distribution	62
		2.2.5	Additional Topic: Short Josephson Junctions: Energy Considerations	63
		2.2.6	The Motion of Josephson Vortices	65
	2.3	Long J	osephson Junctions	68
		2.3.1	The Stationary Sine-Gordon Equation	68
		2.3.2	The Josephson Vortex	70
		2.3.3	Junction Types and Boundary Conditions	73
		2.3.4	Additional Topic: Josephson Current Density Distribution and Maximum Josephson Current	79
		2.3.5	The Pendulum Analog	84
3	He	The Vo	Itage State	89
5	3 1	The Ba	asic Equation of the Lumped Iosephson Junction	90
	5.1	311	The Normal Current: Junction Resistance	90
		3.1.2	The Displacement Current: Junction Capacitance	92
		3.1.3	Characteristic Times and Frequencies	93
		3.1.4	The Fluctuation Current	94
		3.1.5	The Basic Junction Equation	96
	3.2	The Re	esistively and Capacitively Shunted Junction Model	97
		3.2.1	Underdamped and Overdamped Josephson Junctions	100
	3.3	Respor	nse to Driving Sources	102
		3.3.1	Response to a dc Current Source	102
		3.3.2	Response to a dc Voltage Source	107
		3.3.3	Response to ac Driving Sources	107
		3.3.4	Photon-Assisted Tunneling	112
	3.4	Additio Effect	onal Topic: of Thermal Fluctuations	115
		3.4.1	Underdamped Junctions: Reduction of I_c by Premature Switching	117
		3.4.2	Overdamped Junctions: The Ambegaokar-Halperin Theory	118
	3.5	Second	lary Quantum Macroscopic Effects	122
		3.5.1	Quantum Consequences of the Small Junction Capacitance	122

v

		3.5.2	Limiting Cases: The Phase and Charge Regime	125
		3.5.3	Coulomb and Flux Blockade	128
		3.5.4	Coherent Charge and Phase States	130
		3.5.5	Quantum Fluctuations	132
		3.5.6	Macroscopic Quantum Tunneling	133
	3.6	Voltage	e State of Extended Josephson Junctions	139
		3.6.1	Negligible Screening Effects	139
		3.6.2	The Time Dependent Sine-Gordon Equation	140
		3.6.3	Solutions of the Time Dependent Sine-Gordon Equation	141
		3.6.4	Additional Topic: Resonance Phenomena	144
II	Ap	plicatio	ons of the Josephson Effect	153
4	SQU	IDs		157
	4.1	The dc	-SQUID	159
		4.1.1	The Zero Voltage State	159
		4.1.2	The Voltage State	164
		4.1.3	Operation and Performance of dc-SQUIDs	168
		4.1.4	Practical dc-SQUIDs	172
		4.1.5	Read-Out Schemes	176
	4.2	Additio The rf-	onal Topic: SQUID	180
		4.2.1	The Zero Voltage State	180
		4.2.2	Operation and Performance of rf-SQUIDs	182
		4.2.3	Practical rf-SQUIDs	186
	4.3	Additio Other S	onal Topic: SQUID Configurations	188
		4.3.1	The DROS	188
		4.3.2	The SQIF	189
		4.3.3	Cartwheel SQUID	189
	4.4	Instrun	nents Based on SQUIDs	191
		4.4.1	Magnetometers	192
		4.4.2	Gradiometers	194
		4.4.3	Susceptometers	196

		4.4.4	Voltmeters
		4.4.5	Radiofrequency Amplifiers
	4.5	Applic	ations of SQUIDs
		4.5.1	Biomagnetism
		4.5.2	Nondestructive Evaluation
		4.5.3	SQUID Microscopy
		4.5.4	Gravity Wave Antennas and Gravity Gradiometers
		4.5.5	Geophysics
5	Digi	tal Elec	tronics 215
	5.1	Superc	conductivity and Digital Electronics
		5.1.1	Historical development
		5.1.2	Advantages and Disadvantages of Josephson Switching Devices
	5.2	Voltag	e State Josephson Logic
		5.2.1	Operation Principle and Switching Times
		5.2.2	Power Dissipation
		5.2.3	Switching Dynamics, Global Clock and Punchthrough
		5.2.4	Josephson Logic Gates
		5.2.5	Memory Cells
		5.2.6	Microprocessors
		5.2.7	Problems of Josephson Logic Gates
	5.3	RSFQ	Logic
		5.3.1	Basic Components of RSFQ Circuits
		5.3.2	Information in RSFQ Circuits
		5.3.3	Basic Logic Gates
		5.3.4	Timing and Power Supply
		5.3.5	Maximum Speed
		5.3.6	Power Dissipation
		5.3.7	Prospects of RSFQ
		5.3.8	Fabrication Technology
		5.3.9	RSFQ Roadmap
	5.4	Analog	g-to-Digital Converters
		5.4.1	Additional Topic:Foundations of ADCs256
		5.4.2	The Comparator
		5.4.3	The Aperture Time
		5.4.4	Different Types of ADCs

6	The	Josephson Voltage Standard 26	<u>í9</u>
	6.1	Voltage Standards	0
		6.1.1 Standard Cells and Electrical Standards	0
		6.1.2 Quantum Standards for Electrical Units	1
	6.2	The Josephson Voltage Standard	'4
		6.2.1 Underlying Physics	'4
		6.2.2 Development of the Josephson Voltage Standard	'4
		6.2.3 Junction and Circuit Parameters for Series Arrays	'9
	6.3	Programmable Josephson Voltage Standard	31
		6.3.1 Pulse Driven Josephson Arrays	33
7	Sup	erconducting Photon and Particle Detectors 28	35
	7.1	Superconducting Microwave Detectors: Heterodyne Receivers	36
		7.1.1 Noise Equivalent Power and Noise Temperature	36
		7.1.2 Operation Principle of Mixers	37
		7.1.3 Noise Temperature of Heterodyne Receivers	90
		7.1.4 SIS Quasiparticle Mixers	92
		7.1.5 Josephson Mixers	96
	7.2	Superconducting Microwave Detectors: Direct Detectors	97
		7.2.1 NEP of Direct Detectors)8
	7.3	Thermal Detectors)0
		7.3.1 Principle of Thermal Detection)0
		7.3.2 Bolometers)2
		7.3.3 Antenna-Coupled Microbolometers)7
	7.4	Superconducting Particle and Single Photon Detectors	4
		7.4.1 Thermal Photon and Particle Detectors: Microcalorimeters	.4
		7.4.2 Superconducting Tunnel Junction Photon and Particle Detectors	8
	7.5	Other Detectors	28
8	Mic	rowave Applications 32	<u>29</u>
	8.1	High Frequency Properties of Superconductors	30
		8.1.1 The Two-Fluid Model	30
		8.1.2 The Surface Impedance	33
	8.2	Superconducting Resonators and Filters	36
	8.3	Superconducting Microwave Sources	37

9	Sup	erconducting Quantum Bits	339
	9.1	Quantum Bits and Quantum Computers	. 341
		9.1.1 Quantum Bits	. 341
		9.1.2 Quantum Computing	. 343
		9.1.3 Quantum Error Correction	. 346
		9.1.4 What are the Problems?	. 348
	9.2	Implementation of Quantum Bits	. 349
	9.3	Why Superconducting Qubits	. 352
		9.3.1 Superconducting Island with Leads	. 352
II	[A	nhang	355
A	The	Josephson Equations	357
B	Ima	ging of the Maximum Josephson Current Density	361
С	Nun	nerical Iteration Method for the Calculation of the Josephson Current Distribution	363
D	Pho	ton Noise	365
	Ι	Power of Blackbody Radiation	. 365
	II	Noise Equivalent Power	. 367
E	Qub	its	369
	Ι	What is a quantum bit ?	. 369
		I.1 Single-Qubit Systems	. 369
		I.2 The spin-1/2 system	. 371
		I.3 Two-Qubit Systems	. 372
	II	Entanglement	. 373
	III	Qubit Operations	. 375
		III.1 Unitarity	. 375
		III.2 Single Qubit Operations	. 375
		III.3 Two Qubit Operations	. 376
	IV	Quantum Logic Gates	. 377
		IV.1 Single-Bit Gates	. 377
		IV.2 Two Bit Gates	. 379
	V	The No-Cloning Theorem	. 384
	VI	Quantum Complexity	. 385
	VII	The Density Matrix Representation	. 385

•	
	v
	л

F	Two	Level Systems 38	89
	Ι	Introduction to the Problem	89
		I.1 Relation to Spin-1/2 Systems	90
	II	Static Properties of Two-Level Systems	90
		II.1 Eigenstates and Eigenvalues	90
		II.2 Interpretation	91
		II.3 Quantum Resonance	94
	III	Dynamic Properties of Two-Level Systems	95
		III.1 Time Evolution of the State Vector	95
		III.2 The Rabi Formula	95
G	The	Spin 1/2 System 39	99
	Ι	Experimental Demonstration of Angular Momentum Quantization	99
	II	Theoretical Description	01
		II.1 The Spin Space	01
	III	Evolution of a Spin 1/2 Particle in a Homogeneous Magnetic Field	02
	IV	Spin 1/2 Particle in a Rotating Magnetic Field	04
		IV.1 Classical Treatment	04
		IV.2 Quantum Mechanical Treatment	06
		IV.3 Rabi's Formula	07
H	Lite	ature 40	09
	Ι	Foundations of Superconductivity	09
		I.1 Introduction to Superconductivity	09
		I.2 Early Work on Superconductivity and Superfluidity	10
		I.3 History of Superconductivity	10
		I.4 Weak Superconductivity, Josephson Effect, Flux Structures	10
	II	Applications of Superconductivity	11
		II.1 Electronics, Sensors, Microwave Devices	11
		II.2 Power Applications, Magnets, Transportation	12
		II.3 Superconducting Materials	12
I	SI-E	nheiten 41	13
	Ι	Geschichte des SI Systems	13
	II	Die SI Basiseinheiten	15
	III	Einige von den SI Einheiten abgeleitete Einheiten	16
	IV	Vorsätze	18
	V	Abgeleitete Einheiten und Umrechnungsfaktoren	19

J Physikalische Konstanten

List of Figures

1.1	Meissner-Effect	19
1.2	Current transport and decay of a supercurrent in the Fermi sphere picture	20
1.3	Stationary Quantum States	24
1.4	Flux Quantization in Superconductors	25
1.5	Flux Quantization in a Superconducting Cylinder	27
1.6	Experiment by Doll and Naebauer	29
1.7	Experimental Proof of Flux Quantization	29
1.8	Rotating superconducting cylinder	31
1.9	The Josephson Effect in weakly coupled superconductors	32
1.10	Variation of n_s^{\star} and γ across a Josephson junction	35
1.11	Schematic View of a Josephson Junction	36
1.12	Josephson Tunneling	39
2.1	Lumped Josephson Junction	45
2.2	Coupling Energy and Josephson Current	46
2.3	The Tilted Washboard Potential	48
2.4	Extended Josephson Junction	51
2.5	Magnetic Field Dependence of the Maximum Josephson Current	55
2.6	Josephson Current Distribution in a Small Josephson Junction for Various Applied Mag- netic Fields	56
2.7	Spatial Interference of Macroscopic Wave Funktions	57
2.8	The Josephson Vortex	57
2.9	Gaussian Shaped Josephson Junction	59
2.10	Comparison between Measurement of Maximum Josephson Current and Optical Diffrac- tion Experiment	60
2.11	Supercurrent Auto-correlation Function	61
2.12	Magnetic Field Dependence of the Maximum Josephson Current of a YBCO-GBJ	63

2.13	Motion of Josephson Vortices	66
2.14	Magnetic Flux and Current Density Distribution for a Josephson Vortex	70
2.15	Classification of Junction Types: Overlap, Inline and Grain Boundary Junction	74
2.16	Geometry of the Asymmetric Inline Junction	77
2.17	Geometry of Mixed Overlap and Inline Junctions	78
2.18	The Josephson Current Distribution of a Long Inline Junction	80
2.19	The Maximum Josephson Current as a Function of the Junction Length	81
2.20	Magnetic Field Dependence of the Maximum Josephson Current and the Josephson Current Density Distribution in an Overlap Junction	83
2.21	The Maximum Josephson Current as a Function of the Applied Field for Overlap and Inline Junctions	84
3.1	Current-Voltage Characteristic of a Josephson tunnel junction	91
3.2	Equivalent circuit for a Josephson junction including the normal, displacement and fluc- tuation current	92
3.3	Equivalent circuit of the Resistively Shunted Junction Model	97
3.4	The Motion of a Particle in the Tilt Washboard Potential	98
3.5	Pendulum analogue of a Josephson junction	99
3.6	The IVCs for Underdamped and Overdamped Josephson Junctions	01
3.7	The time variation of the junction voltage and the Josephson current	03
3.8	The RSJ model current-voltage characteristics	05
3.9	The RCSJ Model IVC at Intermediate Damping	07
3.10	The RCJ Model Circuit for an Applied dc and ac Voltage Source	08
3.11	Overdamped Josephson Junction driven by a dc and ac Voltage Source	10
3.12	Overdamped Josephson junction driven by a dc and ac Current Source $\ldots \ldots \ldots \ldots 1$	11
3.13	Shapiro steps for under- and overdamped Josephson junction	12
3.14	Photon assisted tunneling	13
3.15	Photon assisted tunneling in SIS Josephson junction	13
3.16	Thermally Activated Phase Slippage	16
3.17	Temperature Dependence of the Thermally Activated Junction Resistance 1	19
3.18	RSJ Model Current-Voltage Characteristics Including Thermally Activated Phase Slippage 1	20
3.19	Variation of the Josephson Coupling Energy and the Charging Energy with the Junction Area	24
3.20	Energy diagrams of an isolated Josephson junction	27
3.21	The Coulomb Blockade	28

3.22	The Phase Blockade
3.23	The Cooper pair box
3.24	Double well potential for the generation of phase superposition states
3.25	Macroscopic Quantum Tunneling
3.26	Macroscopic Quantum Tunneling at Large Damping
3.27	Mechanical analogue for phase dynamics of a long Josephson junction
3.28	The Current Voltage Characteristic of an Underdamped Long Josephson Junction 145
3.29	Zero field steps in IVCs of an annular Josephson junction
4.1	The dc-SQUID
4.2	Maximum Supercurrent versus Applied Magnetic Flux for a dc-SQUID at Weak Screening162
4.3	Total Flux versus Applied Magnetic Flux for a dc SQUID at $\beta_L > 1$
4.4	Current-voltage Characteristics of a dc-SQUID at Negligible Screening
4.5	The pendulum analogue of a dc SQUID
4.6	Principle of Operation of a dc-SQUID
4.7	Energy Resolution of dc-SQUIDs
4.8	The Practical dc-SQUID
4.9	Geometries for thin film SQUID washers
4.10	Flux focusing effect in a $YBa_2Cu_3O_{7-\delta}$ washer $\ldots \ldots 175$
4.11	The Washer dc-SQUID
4.12	The Flux Modulation Scheme for a dc-SQUID
4.13	The Modulation and Feedback Circuit of a dc-SQUID
4.14	The rf-SQUID
4.15	Total flux versus applied flux for a rf-SQUID
4.16	Operation of rf-SQUIDs
4.17	Tank voltage versus rf-current for a rf-SQUID
4.18	High T_c rf-SQUID
4.19	The double relaxation oscillation SQUID (DROS)
4.20	The Superconducting Quantum Interference Filter (SQIF)
4.21	Input Antenna for SQUIDs
4.22	Various types of thin film SQUID magnetometers
4.23	Magnetic noise signals
4.24	Magnetically shielded room
4.25	Various gradiometers configurations

4.26	Miniature SQUID Susceptometer
4.27	SQUID Radio-frequency Amplifier
4.28	Multichannel SQUID Systems
4.29	Magnetocardiography
4.30	Magnetic field distribution during R peak
4.31	SQUID based nondestructive evaluation
4.32	Scanning SQUID microscopy
4.33	Scanning SQUID microscopy images
4.34	Gravity wave antenna
4.35	Gravity gradiometer
5.1	Cryotron
5.2	Josephson Cryotron
5.3	Device performance of Josephson devices
5.4	Principle of operation of a Josephson switching device
5.5	Output current of a Josephson switching device
5.6	Threshold characteristics for a magnetically and directly coupled gate
5.7	Three-junction interferometer gate
5.8	Current injection device
5.9	Josephson Atto Weber Switch (JAWS)
5.10	Direct coupled logic (DCL) gate
5.11	Resistor coupled logic (RCL) gate
5.12	4 junction logic (4JL) gate
5.13	Non-destructive readout memory cell
5.14	Destructive read-out memory cell
5.15	4 bit Josephson microprocessor
5.16	Josephson microprocessor
5.17	Comparison of latching and non-latching Josephson logic
5.18	Generation of SFQ Pulses
5.19	dc to SFQ Converter
5.20	Basic Elements of RSFQ Circuits
5.21	RSFQ memory cell
5.22	RSFQ logic
5.23	RSFQ OR and AND Gate

5.24	RSFQ NOT Gate
5.25	RSFQ Shift Register
5.26	RSFQ Microprocessor
5.27	RSFQ roadmap
5.28	Principle of operation of an analog-to-digital converter
5.29	Analog-to-Digital Conversion
5.30	Semiconductor and Superconductor Comparators
5.31	Incremental Quantizer
5.32	Flash-type ADC 265
5.33	Counting-type ADC
6.1	Weston cell
6.2	The metrological triangle for the electrical units
6.3	IVC of an underdamped Josephson junction under microwave irradiation
6.4	International voltage comparison between 1920 and 2000
6.5	One-Volt Josephson junction array
6.6	Josephson series array embedded into microwave stripline
6.7	Microwave design of Josephson voltage standards
6.8	Adjustment of Shapiro steps for a series array Josephson voltage standard 281
6.9	IVC of overdamped Josephson junction with microwave irradiation
6.10	Programmable Josephson voltage standard
7.1	Block diagram of a heterodyne receiver
7.2	Ideal mixer as a switch
7.3	Current response of a heterodyne mixer
7.4	IVCs and IF output power of SIS mixer
7.5	Optimum noise temperature of a SIS quasiparticle mixer
7.6	Measured DSB noise temperature of a SIS quasiparticle mixers
7.7	High frequency coupling schemes for SIS mixers
7.8	Principle of thermal detectors
7.9	Operation principle of superconducting transition edge bolometer
7.10	Sketch of a HTS bolometer
7.11	Specific detectivity of various bolometers
7.12	Relaxation processes in a superconductor after energy absorption
7.13	Antenna-coupled microbolometer

Schematic illustration of the hot electron bolometer mixer
Hot electron bolometer mixers with different antenna structures
Transition-edge sensors
Transition-edge sensors
Functional principle of a superconducting tunnel junction detector
Circuit diagram of a superconducting tunnel junction detector
Energy resolving power of STJDs
Quasiparticle tunneling in SIS junctions
Quasiparticle trapping in STJDs
STJDs employing lateral quasiparticle trapping
Superconducting tunnel junction x-ray detector
Equivalent circuit for the two-fluid model
Characteristic frequency regimes for a superconductor
Surface resistance of Nb and Cu
Konrad Zuse 1945
Representation of a Qubit State as a Vector on the Bloch Sphere
Operational Scheme of a Quantum Computer
Quantum Computing: What's it good for?
Shor, Feynman, Bennett and Deutsch
Qubit Realization by Quantum Mechanical Two level System
Use of Superconductors for Qubits
Superconducting Island with Leads
The Bloch Sphere S^2
The Spin-1/2 System
Entanglement – an artist's view
Classical Single-Bit Gate
Quantum NOT Gate
Classical Two Bit Gate
Reversible and Irreversible Logic
Reversible Classical Logic
Reversible XOR (CNOT) and SWAP Gate
The Controlled U Gate

E.11	Density Matrix for Pure Single Qubit States	386
E.12	Density Matrix for a Coherent Superposition of Single Qubit States	387
F.1	Energy Levels of a Two-Level System	392
F.2	The Benzene Molecule	394
F.3	Graphical Representation of the Rabi Formula	396
G.1	The Larmor Precession	100
G.2	The Rotating Reference Frame	104
G.3	The Effective Magnetic Field in the Rotating Reference Frame	405
G.4	Rabi's Formula for a Spin 1/2 System 4	108

List of Tables

5.1	Switching delay and power dissipation for various types of logic gates
5.2	Josephson 4 kbit RAM characteristics (organization: 4096 word x 1 bit, NEC)
5.3	Performance of various logic gates
5.4	Possible applications of superconductor digital circuits (source: SCENET 2001)
5.5	Performance of various RSFQ based circuits
7.1	Characteristic materials properties of some superconductors
8.1	Important high-frequency characteristic of superconducting and normal conducting 334
E.1	Successive measurements on a two-qubit state showing the results A and B with the corresponding probabilities $P(A)$ and $P(B)$ and the remaining state after the measurement

Chapter D

Photon Noise

I Power of Blackbody Radiation

Bolometers used for the detection of thermal radiation are influenced by thermal backgrounds. Therefore, we briefly summarize some aspects of thermal radiation. It is usual to work with an optical system which limits the beam to an area A and a solid angle Ω , and has filters with transmittance $\tau(f)$, where f is the optical frequency. The power transmitted through such a system from a blackbody source with Planck spectral brightness B(f,T) can be expressed as

$$P = \int_{0}^{\infty} P_f df = \int_{0}^{\infty} A\Omega T(f) B(f,T) df .$$
(I.1)

The throughput $A\Omega$ in sr m² is an invariant in an optical system, as can easily be proved from geometrical optics.

When diffraction is important, the throughput depends on the wavelength λ . The antenna theorem states that for a single spatial mode, or diffraction limited beam, the throughput is exactly $A\Omega = \lambda^2$. This principle is easily illustrated by using Fraunhoffer diffraction theory to compute the solid angle of divergence Ω of a plane wave after passing through a circular aperture of area A. When the solid angle or the area is not uniformly illuminated, an equivalent solid angle (or area) must be used for exact results. Infrared telescopes often use throughputs somewhat larger than the diffraction limit. For a uniformly illuminated circular aperture, 84% of the energy from a point source appears in a throughput $A\Omega = 3.7\lambda^2$. Spatially incoherent light can be thought of as being made up from many modes. The number of modes is $N = A\Omega/\lambda^2$ for a single polarization. This picture can also be applied for the intermediate case of partially coherent light, although a rigorous treatment is complicated.¹

A well-known result of thermal physics is that for a blackbody source the power per mode is

$$P_f df = \frac{hf df}{\exp(hf/k_B T) - 1} . \tag{I.2}$$

This expression approaches k_BTdf for $hf \ll k_BT$. The power P(f,T)df in a multimode source is just the number of modes times the power per mode, i.e. $P(f,T)df = \frac{c}{2}u(f,T)df = \frac{c}{2}hfnD(f)$. Here, u(f,T)

¹J. M. Lamarre, Appl. Opt. 25, 870 (1986).

is the energy spectral density, *n* the occupation number and $D(f) = 4f^2/c^3$ the spectral density of the modes (for two polarizations). This gives the Planck result for the spectral brightness of a blackbody to

$$B(f,T) df = \frac{2hf^3 df}{c^2 [\exp(hf/k_B T) - 1]} .$$
(I.3)

This expression implicitly identifies the thermal equilibrium number $n = [\exp(hf/k_BT) - 1]^{-1}$ of photons per standing wave mode in a box at temperature T with the number of photons per s per Hz of infrared bandwidth in a spatial mode propagating in free space. With this identification we can use the textbook expression for the thermal average variance in the number of photons per mode inside the box, $\langle (\Delta n)^2 \rangle =$ $n+n^2$ to compute the fluctuations in the number of photons arriving per second from the free space beam. Note that for $hf \ll k_BT$ we have $n \ll 1$ and the fluctuations obey Poisson statistics, $\langle (\Delta n)^2 \rangle = n$. In this case, the photon arrival is random. When there are many photons per mode, $n \gg 1$, the photons arrive in bunches and we have $\langle (\Delta n)^2 \rangle = n^2$.

Since a bolometer detects the incoming power, we are interested in the mean square energy fluctuation, which can be written as $h^2 f^2 \langle (\Delta n)^2 \rangle$. If we make the simple assumption that fluctuations in energy in different modes and in different infrared bandwidths are uncorrelated, then their mean square fluctuations are additive. Then the mean square fluctuation in the energy arriving within the time interval of 1 s is $\int h^2 f^2 2N(n+n^2) df$, where N is the number of contributing modes. Since the bandwidth associated with a 1 s unweighted average is 1/2 Hz, the mean square noise power per unit post-detection bandwidth B referred to the absorbed power at the input is

$$\frac{P_N^2}{B} = 2 \int 2Nn \, (hf)^2 \, df + 2 \int (2Nnhf)^2 \, \frac{hf}{2N} \, df
= 2 \int P_f \, hf \, df + \int P_f^2 \, \frac{c^2}{A\Omega^2 f^2} \, df ,$$
(I.4)

where we have used $P_f = 2Nnhf$ for the spectral power absorbed in the bolometer and $N = A\Omega/\lambda^2 = a\Omega f^2/c^2$ for the number of modes. Note that Planck's constant *h* does not appear in the second term, which is a property of classical waves.

The first term in (D.I.4) can be obtained more directly. For Poisson statistics, the mean square fluctuation in the number of photons arriving in a time interval of 1 s is just equal to the number of photons arriving, i.e. $\langle (\Delta n)^2 \rangle = P_f/hf$. If we multiply by $h^2 f^2$ to obtain fluctuations in power and by 2B to convert a 1 s average to a bandwidth of B Hz, we obtain the first term in (D.I.4). This term has been verified experimentally in many experiments. The second term, by contrast, has not been measured unambiguously.

Although the form given in (D.I.4) appears frequently in the literature,^{2,3,4} there are theoretical arguments and indirect experimental data, which show that it is not correct. The argument can be understood from the central limit theorem of probability theory. When the fluctuations from enough modes are combined, the resulting distribution should be Gaussian (of which Poisson statistics is a special case). It has been argued that the second term in (D.I.4) should have a factor $q = 2A\Omega\Delta f\Delta T/\lambda^2$ in the denominator.^{5,6} Here, q is the number of modes of one polarization detected in the frequency band Δf during the time ΔT , which is a very large number for most bolometric systems. Indeed, experimental evidence for this averaging effect was found in the scattering of visible light from dielectric spheres.⁷ Although we

⁶J. M. Lamarre, Appl. Opt. **25**, 870 (1986).

²J. C Mather, Appl. Opt. 23, 3181 (1984); J. C. Mather, Appl. Opt. 23, 584 (1984).

³K. M. van Vliet, Appl. Opt. **6**, 1145 (1967).

⁴J. C. Mather, Appl. Opt. **21**, 1125 (1982).

⁵E. Jakeman and E. R. Pike, J. Phys. A (Proc. Phys. Soc.) **1**, 128 (1968).

⁷E. Jakeman, C. J. Oliver, and E. R. Pike, J. Phys. A (Proc. Phys. Soc.) **1**, 406 (1968).

will use the full expression (D.I.4) with the factor q in the following, it may prove that the second term can be neglected in almost all practical situations.

We have to generalize our discussion now to treat real systems, which have sources with emissivity ε , cold filters with transmissivity $\tau(f)$, and bolometers with absorptivity η . We will assume that the bolometer is cold enough that fluctuations in the power emitted by the bolometer can be neglected. The number of photons per s per mode and per Hz, which is $n = [\exp(hf/k_BT) - 1]^{-1}$ for a blackbody becomes $n = \varepsilon \tau \eta [\exp(hf/k_BT) - 1]^{-1}$ inside the bolometer, where the nonlinear processing takes place. For T=300 K and $\varepsilon \tau \eta = 1$ we have n = 1 at $\lambda \simeq 100 \,\mu$ m. For the more realistic case, $\varepsilon \tau \eta = 0.1$, we have n = 1 at $\lambda \simeq 1$ mm. Consequently, the first term in (D.I.4) typically dominates for infrared systems and the second term with q = 1 would be important for millimeter wave systems. Although the two limits of photon noise are analogous to the Rayleigh-Jeans and Wien limits of the Planck theory, it is clear that the fundamental variable is n, the number of photons per second in one mode in one Hz of infrared bandwidth, and not hf/k_BT .

II Noise Equivalent Power

A frequently used figure of merit is the noise equivalent power (NEP), which is defined as the incident signal power required to obtain a signal equal to the noise in a one Hz bandwidth. That is, the NEP is a measure of signal to noise ratio (SNR) and not just noise. If we refer the NEP to the inside of the detector, the signal power absorbed in the detector that is required is just $NEP_{abs} = P_N B^{-1/2}$ according to (D.I.4). Usually, one refers however the NEP to the detector input. The signal power incident on the detector required to produce SNR=1 is then

NEP² =
$$\frac{2}{\eta^2} \int P_f hf df + \frac{1}{q\eta^2} \int P_f^2 \frac{c^2}{A\Omega^2 f^2} df$$
, (II.5)

where P_f is the power absorbed in the detector. Expression (D.II.5) is used to calculate the photon noise contribution to the detector noise for an existing system when the throughput $A\Omega$ is known from the optical geometry and the absorbed power spectral density can be estimated from the filter bands, the bolometer output and the absorbed power responsivity *S*. Although originally introduced to describe photoconductors, the term BLIP (Background Limited Infrared Photodetector) is often used to describe any detector whose noise in a given application comes only from photon fluctuations in the infrared background.

Calculations of the background power and photon noise expected from thermal sources are important in the design of bolometric detector systems. From (D.I.1) the absorbed power in the frequency band from f_1 to f_2 is

$$P = \frac{2k_B^4}{c^2 h^3} T^4 A \Omega \, \varepsilon \tau \eta \int_{x_1}^{x_2} \frac{x^3}{\exp(x) - 1} \, dx \quad , \tag{II.6}$$

where we have used the substitution $x = hf/k_BT$. An analogous expression for the photon noise limited NEP referred to the detector input is obtained by writing the absorbed power spectral density in (D.II.5) as $P_f = A\Omega \epsilon T \eta B(f,T)$. We obtain

$$NEP^{2} = \frac{4k_{B}^{5}}{c^{2}h^{3}} \frac{T^{5}A\Omega \varepsilon \tau}{\eta} \int_{x_{1}}^{x_{2}} \frac{x^{4}}{\exp(x) - 1} dx + \frac{\varepsilon \tau \eta}{q} \int_{x_{1}}^{x_{2}} \frac{x^{4}}{[\exp(x) - 1]^{2}} dx .$$
(II.7)

We see that NEP² $\propto AT^5$, i.e. the photon noise increases strongly with increasing temperature and increasing detector area. Expressions related to (D.II.7) are seen in the literature for the NEP or the noise equivalent photon rate (NEN) of photon detectors such as photoconductors and photovoltaic diodes. The derivation differs from that given above in that the mean square fluctuation in the photon rate $\langle (\Delta n)^2 \rangle$ for different infrared bandwidths are added directly and not multiplied by $(hf)^2$ to obtain energy fluctuations before adding as was done above.